

# **Radiation Hardened Quad Voltage Comparator**

### HS-139RH, HS-139EH

The Radiation Hardened HS-139RH, HS-139EH consists of four independent single or dual supply voltage comparators on a single monolithic substrate. The common mode input voltage range includes ground, even when operated from a single supply and the low supply current makes these comparators suitable for low power applications. These types were designed to directly interface with TTL and CMOS.

The HS-139RH, HS-139EH is fabricated on our dielectrically isolated Rad Hard Silicon Gate (RSG) process, which provides an immunity to Single Event Latch-up and the capability of highly reliable performance in any radiation environment.

Specifications for Rad Hard QML devices are controlled by the Defense Logistics Agency Land and Maritime (DLA). The SMD numbers listed below must be used when ordering.

Detailed Electrical Specifications for the HS-139RH, HS-139EH are contained in <u>SMD 5962-98613</u>. A "hot-link" is provided on our homepage with instructions for downloading. www.intersil.com/spacedefense/newsafclasst.asp

#### **Features**

- QML Qualified Per MIL-PRF-38535 Requirements
- Radiation Environment
  - Latch-up Free Under any Conditions

  - SEU LET Threshold . . . . . . . . . . . . 20MeV/cm<sup>2</sup>/mg
  - Low Dose Rate Effects Immunity
- 100V Output Voltage Withstand Capability
- ESD Protection to >3000V
- Differential Input Voltage Range Equal to the Supply Voltage
- Input Offset Voltage ( $V_{10}$ ) . . . . . . . . . . . . . . . . . 2mV (Max)
- Quiescent Supply Current . . . . . . . . . . . . . 2mA (Max)
- Pb-Free (RoHS Compliant)

### **Applications**

- Pulse Generators
- Timing Circuitry
- · Level Shifting
- · Analog-to-Digital Conversion

### **Ordering Information**

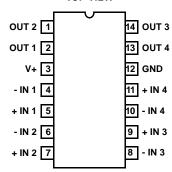
ORDERING NUMBER (Note)	INTERNAL MKT. NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE (RoHS Compliant)	PACKAGE DRAWING NUMBER
5962F9861303VCC	HS1-139EH-Q	Q 5962F98 61303VCC	-55 to +125	14 Ld SBDIP	D14.3
5962F9861301VCC	HS1-139RH-Q	Q 5962F98 61301VCC	-55 to +125	14 Ld SBDIP	D14.3
5962F9861301QCC	HS1-139RH-8	Q 5962F98 61301QCC	-55 to +125	14 Ld SBDIP	D14.3
HS1-139RH/PROTO	HS1-139RH/PROTO	HS1-139RH/PROTO	-55 to +125	14 Ld SBDIP	D14.3
5962F9861301VXC	HS9-139RH-Q	Q 5962F98 61301VXC	-55 to +125	14 Ld FLATPACK	K14.A
5962F9861301QXC	HS9-139RH-8	Q 5962F98 61301QXC	-55 to +125	14 Ld FLATPACK	K14.A
5962F9861302VXC	HS9-139EH-Q	Q 5962F98 61302VXC	-55 to +125	14 Ld FLATPACK	K14.A
HS9-139RH/PROTO	HS9-139RH/PROTO	HS9-139RH /PROTO	-55 to +125	14 Ld FLATPACK	K14.A

NOTE: These Intersil Pb-free Hermetic packaged products employ 100% Au plate - e4 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations.

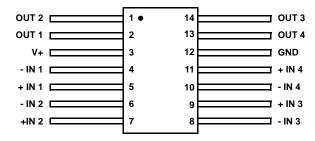
### HS-139RH, HS-139EH

# **Pin Configurations**

HS-139RH, HS-139EH (SBDIP CDIP2-T14) TOP VIEW



HS-139RH, HS-139EH (FLATPACK CDFP3-F14) TOP VIEW



### **Die Characteristics**

#### **DIE DIMENSIONS:**

 $3750\mu m \ x \ 2820\mu m \ (148 \ mils \ x \ 111 \ mils)$   $483\mu m \pm 25.4\mu m \ (19 \ mils \pm 1 \ mil)$ 

#### **INTERFACE MATERIALS:**

#### **Glassivation:**

Type: Silox (SiO<sub>2</sub>) Thickness: 8.0kÅ ±1.0kÅ

#### **Top Metallization:**

Type: AlSiCu

Thickness: 16.0kÅ ±2kÅ

#### Substrate:

Radiation Hardened Silicon Gate, Dielectric Isolation

#### **Backside Finish:**

Silicon

#### **ASSEMBLY RELATED INFORMATION:**

#### **Substrate Potential:**

Unbiased (DI)

#### **ADDITIONAL INFORMATION:**

#### **Worst Case Current Density:**

 $<2.0 \times 10^5 \text{ A/cm}^2$ 

#### **Transistor Count:**

49

# **Metallization Mask Layout**

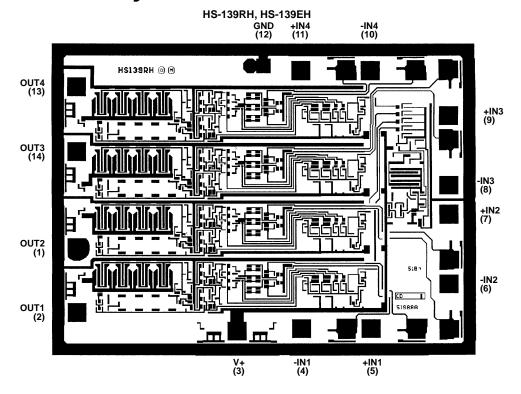


TABLE 1. HS-139RH, HS-139EH PAD COORDINATES

		RELATIVE TO PIN 1		
PIN NUMBER	PAD NAME	X COORDINATES	Y COORDINATES	
1	OUT 2	0	0	
2	OUT 1	0	-535	
3	V+	1323	-688	
4	-IN 1	1862	-670	
5	+IN 1	2439	-670	
6	-IN 2	3084	-299	
7	+IN 2	3084	278	
8	-IN 3	3084	518	
9	+IN 3	3084	1095	
10	-IN 4	2439	1466	
11	+IN 4	1862	1466	
12	GND	1550	1503	
13	OUT 4	0	1331	
14	OUT 3	0	796	

NOTE: Dimensions in microns

For additional products, see  $\underline{\text{www.intersil.com/product tree}}$ 

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